NSN 5961-00-229-7900

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-229-7900 **Inclosure Material:** Plastic **Overall Length:** 0.425 inches **Terminal Length:** 0.750 inches **Overall Diameter:** 0.385 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1000.0 reverse voltage, peak **Current Rating Per Characteristic:** 30.00 amperes forward current, average pascal **Power Rating Per Characteristic:** 2.8 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 145.0 degrees celsius junction **Precious Material And Location:** Terminal surface silver **Precious Material:** Silver **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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